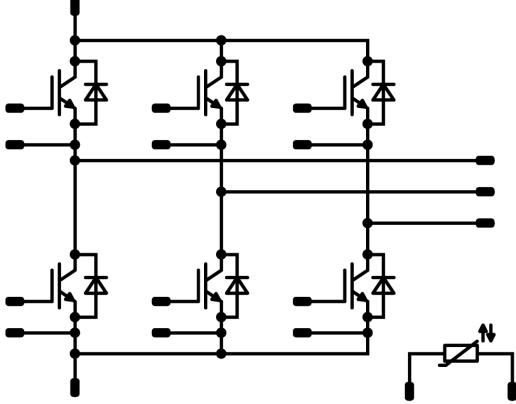




Vincotech

| flow90PACK 1 | | 1200 V / 8 A |
|--|--|---|
| Features | | flow90 1 housing |
| <ul style="list-style-type: none">• Trench Fieldstop IGBT4 Technology• Supports designs with 90° mounting angle between heatsink and PCB• Clip-in PCB mounting• Clip or screw hetasink mounting | |  |
| Target applications | | Schematic |
| <ul style="list-style-type: none">• Motor Drives | |  |
| Types | | |
| <ul style="list-style-type: none">• V23990-P707-F40-PM | | |



Vincotech

Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Conditions | Value | Unit |
|-----------------------------------|------------|---|----------|------------------|
| Inverter Switch | | | | |
| Collector-emitter voltage | V_{CES} | | 1200 | V |
| Collector current (DC current) | I_C | $T_j = T_{jmax}$ $T_s = 80 \text{ }^\circ\text{C}$ | 16 | A |
| Repetitive peak collector current | I_{CRM} | t_p limited by T_{jmax} | 24 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80 \text{ }^\circ\text{C}$ | 61 | W |
| Gate-emitter voltage | V_{GES} | | ± 20 | V |
| Short circuit ratings | t_{SC} | $V_{GE} = 15 \text{ V}$, $V_{CC} = 800 \text{ V}$ $T_j = 150 \text{ }^\circ\text{C}$ | 10 | μs |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |

Inverter Diode

| | | | | |
|---------------------------------|------------|--|------|------------------|
| Peak repetitive reverse voltage | V_{RRM} | | 1200 | V |
| Forward current (DC current) | I_F | $T_j = T_{jmax}$ $T_s = 80 \text{ }^\circ\text{C}$ | 20 | A |
| Repetitive peak forward current | I_{FRM} | t_p limited by T_{jmax} | 20 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80 \text{ }^\circ\text{C}$ | 46 | W |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |

Module Properties

| Thermal Properties | | | | |
|---|-----------|--|----------------------------|------------------|
| Storage temperature | T_{stg} | | -40...+125 | $^\circ\text{C}$ |
| Operation temperature under switching condition | T_{jop} | | -40...+($T_{jmax} - 25$) | $^\circ\text{C}$ |

Isolation Properties

| | | | | | |
|----------------------------|------------|------------------|-----------------------|-----------|----|
| Isolation voltage | V_{isol} | DC Test Voltage* | $t_p = 2 \text{ s}$ | 6000 | V |
| Isolation voltage | V_{isol} | AC Voltage | $t_p = 1 \text{ min}$ | 2500 | V |
| Creepage distance | | | | min. 12,7 | mm |
| Clearance | | | | 11,67 | mm |
| Comparative Tracking Index | CTI | | | > 200 | |

*100 % tested in production



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Values | | | Unit |
|-----------|--------|--------------|--------------|--------------|--------------|-----------|------------|--------|-----|-----|------|
| | | V_{GE} [V] | V_{GS} [V] | V_{CE} [V] | V_{DS} [V] | I_C [A] | T_j [°C] | Min | Typ | Max | |

Inverter Switch

Static

| | | | | | | | | | | |
|--------------------------------------|--------------|--------------------------|----|------|---------|-----------|------|--------------|---------------------|----|
| Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{CE} = V_{GE}$ | | | 0,00015 | 25 | 5,3 | 5,8 | 6,3 | V |
| Collector-emitter saturation voltage | V_{CEsat} | | 15 | | 8 | 25 150 | 1,58 | 1,88 2,16 | 2,07 ⁽¹⁾ | V |
| Collector-emitter cut-off current | I_{CES} | | 0 | 1200 | | 25 | | | 1 | μA |
| Gate-emitter leakage current | I_{GES} | | 20 | 0 | | 25 | | | 120 | nA |
| Internal gate resistance | r_g | | | | | | | None | | Ω |
| Input capacitance | C_{res} | $f = 1 \text{ Mhz}$ | 0 | 25 | 25 | 25 | 490 | | | pF |
| Reverse transfer capacitance | C_{res} | | | | | | | | | pF |
| Gate charge | Q_g | $V_{CC} = 960 \text{ V}$ | 15 | | 8 | 25 | | 53 | | nC |

Thermal

| | | | | | | | | | | |
|--|---------------|--|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink ⁽²⁾ | $R_{th(j-s)}$ | $\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 1,57 | | K/W |
|--|---------------|--|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|-----------------------------|--------------|---|----------|-----|---|-----------|--|-----------------|--|-----|
| Turn-on delay time | $t_{d(on)}$ | $R_{gon} = 64 \Omega$ $R_{goft} = 64 \Omega$ | ± 15 | 600 | 8 | 25 150 | | 106,4 104,4 | | ns |
| Rise time | t_r | | | | | 25 150 | | 25,4 28,4 | | ns |
| Turn-off delay time | $t_{d(off)}$ | | | | | 25 150 | | 227,2 296,8 | | ns |
| Fall time | t_f | | | | | 25 150 | | 67,96 140,05 | | ns |
| Turn-on energy (per pulse) | E_{on} | | | | | 25 150 | | 0,662 1,01 | | mWs |
| Turn-off energy (per pulse) | E_{off} | | | | | 25 150 | | 0,482 0,807 | | mWs |



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Values | | | Unit |
|-----------|--------|--------------|--------------|--------------|--------------|-----------|------------|--------|-----|-----|------|
| | | V_{GE} [V] | V_{GS} [V] | V_{CE} [V] | V_{DS} [V] | I_C [A] | T_j [°C] | Min | Typ | Max | |
| | | | | | | | | | | | |

Inverter Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|----------------|--|--|----|-----------|------|--------------|---------------------|----|
| Forward voltage | V_F | | | | 10 | 25 150 | 1,35 | 1,77 1,69 | 2,05 ⁽¹⁾ | V |
| Reverse leakage current | I_R | $V_r = 1200$ V | | | 25 | | | | 2,7 | µA |

Thermal

| | | | | | | | | | | |
|--|---------------|---------------------------------------|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink ⁽²⁾ | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4$ W/mK (PSX) | | | | | | 2,07 | | K/W |
|--|---------------|---------------------------------------|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|---------------------------------------|----------------------|--------------------------------------|----------|-----|---|-----------|--|------------------|--|------|
| Peak recovery current | I_{RRM} | $di/dt=383$ A/µs $di/dt=345$ A/µs | ± 15 | 600 | 8 | 25 150 | | 7,53 8,82 | | A |
| Reverse recovery time | t_{rr} | | | | | 25 150 | | 270,53 447,65 | | ns |
| Recovered charge | Q_r | | | | | 25 150 | | 0,842 1,72 | | µC |
| Reverse recovered energy | E_{rec} | | | | | 25 150 | | 0,295 0,643 | | mWs |
| Peak rate of fall of recovery current | $(di_{rr}/dt)_{max}$ | | | | | 25 150 | | 28,88 23,79 | | A/µs |



Vincotech

Characteristic Values

| Parameter | Symbol | Conditions | | | | | Values | | | Unit |
|-----------|--------|--------------|--------------|--------------|--------------|-----------|------------|-----|-----|------|
| | | V_{GE} [V] | V_{GS} [V] | V_{CE} [V] | V_{DS} [V] | I_C [A] | T_j [°C] | Min | Typ | Max |
| | | | | | | | | | | |

Thermistor

Static

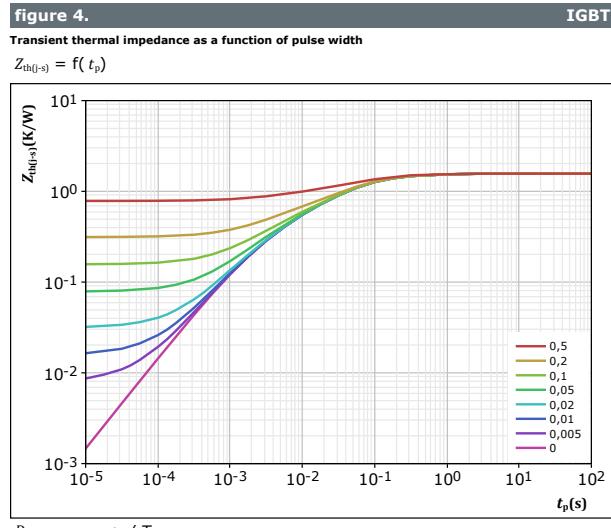
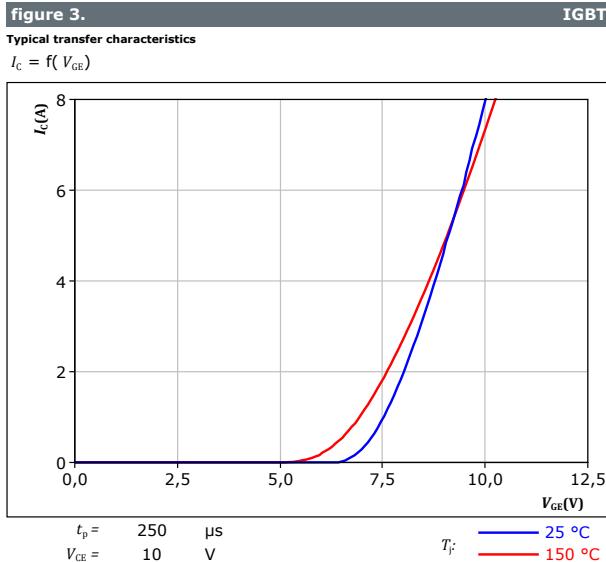
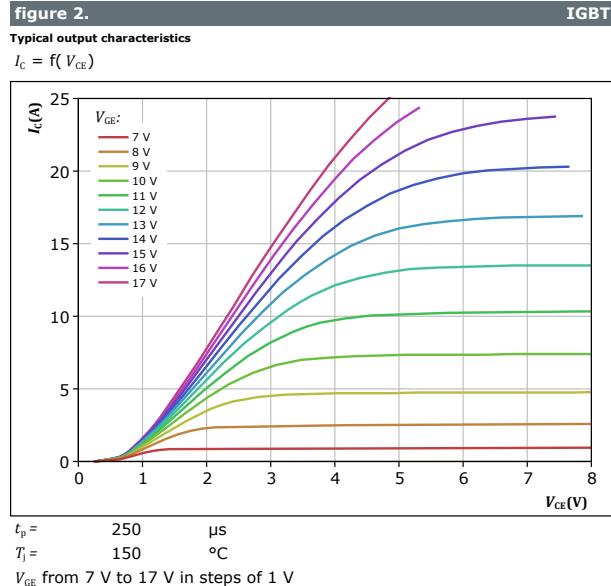
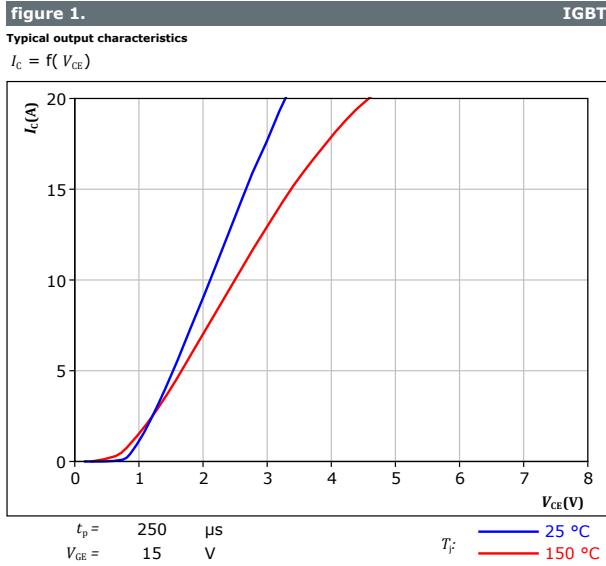
| | | | | | | | | | | | |
|--------------------------------|----------------|-------------------------|--|--|--|-----|--|------|---|------|---|
| Rated resistance | R | | | | | 25 | | 22 | | kΩ | |
| Deviation of R_{100} | $A_{R/R}$ | $R_{100} = 1486 \Omega$ | | | | 100 | | -12 | | 14 | % |
| Power dissipation | P | | | | | | | 200 | | mW | |
| Power dissipation constant | d | | | | | 25 | | 2 | | mW/K | |
| B-value | $B_{(25/50)}$ | Tol. ±3 % | | | | | | 3950 | | K | |
| B-value | $B_{(25/100)}$ | Tol. ±3 % | | | | | | 3998 | | K | |
| Vincotech Thermistor Reference | | | | | | | | | B | | |

(¹) Value at chip level

(²) Only valid with pre-applied Vincotech thermal interface material.

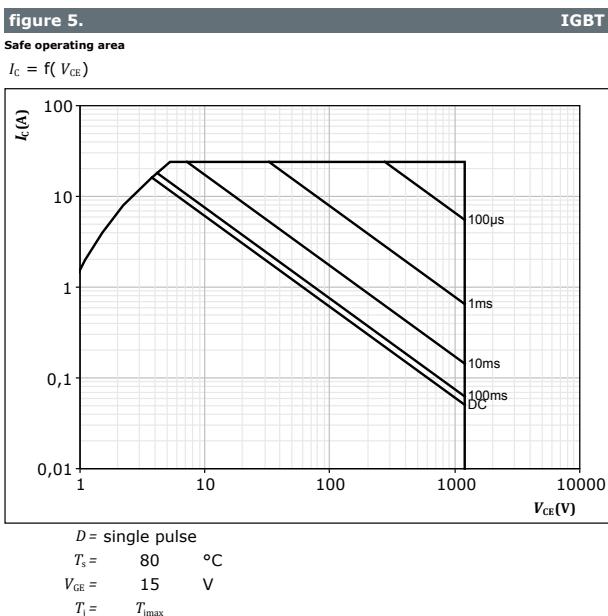


Inverter Switch Characteristics





Inverter Switch Characteristics

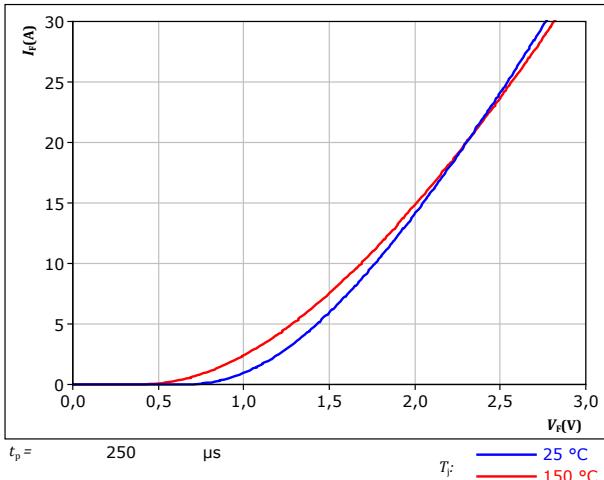


Inverter Diode Characteristics

figure 6.

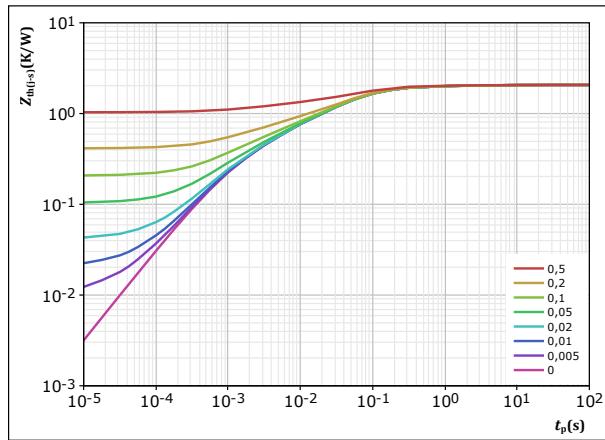
Typical forward characteristics

$$I_F = f(V_F)$$

**FWD****figure 7.**

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$

**FWD**

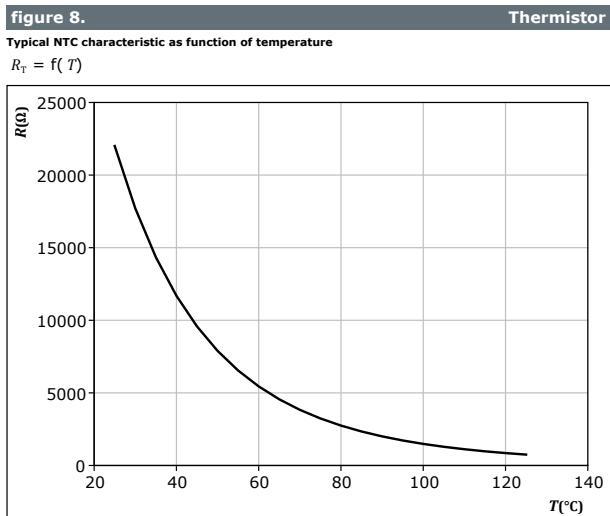
$$D = \frac{t_p / T}{2,066} \quad K/W$$

FWD thermal model values

| R (K/W) | τ (s) |
|-----------|------------|
| 5,09E-02 | 4,26E+00 |
| 1,55E-01 | 5,03E-01 |
| 7,75E-01 | 7,89E-02 |
| 5,33E-01 | 2,68E-02 |
| 3,54E-01 | 5,03E-03 |
| 1,97E-01 | 9,09E-04 |



Thermistor Characteristics





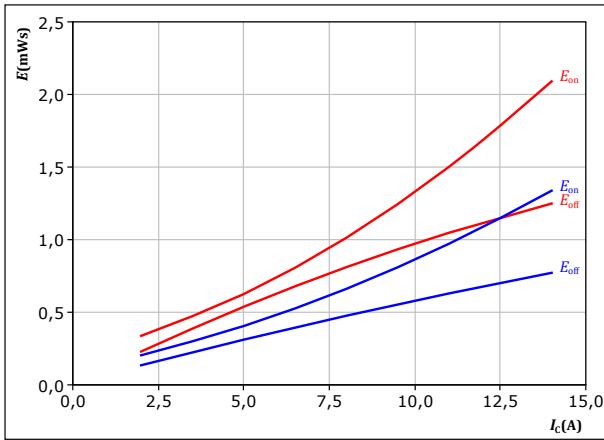
Vincotech

Inverter Switching Characteristics

figure 9.

Typical switching energy losses as a function of collector current

$$E = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ R_{gon} &= 64 \Omega \\ R_{goff} &= 64 \Omega \end{aligned}$$

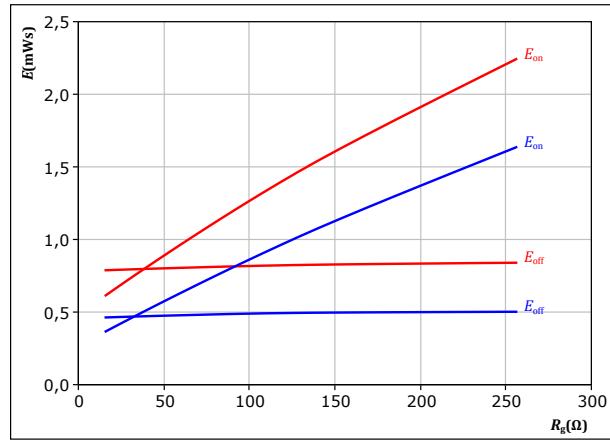
$$T_f: \quad \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{---} & 150^\circ\text{C} \end{array}$$

IGBT

figure 10.

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ I_c &= 8 \text{ A} \end{aligned}$$

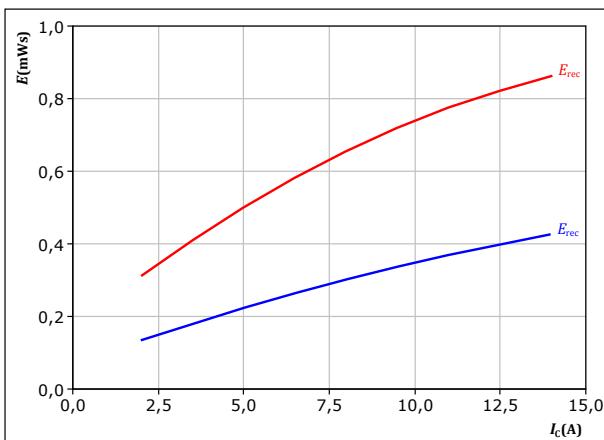
$$T_f: \quad \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{---} & 150^\circ\text{C} \end{array}$$

IGBT

figure 11.

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ R_{gon} &= 64 \Omega \end{aligned}$$

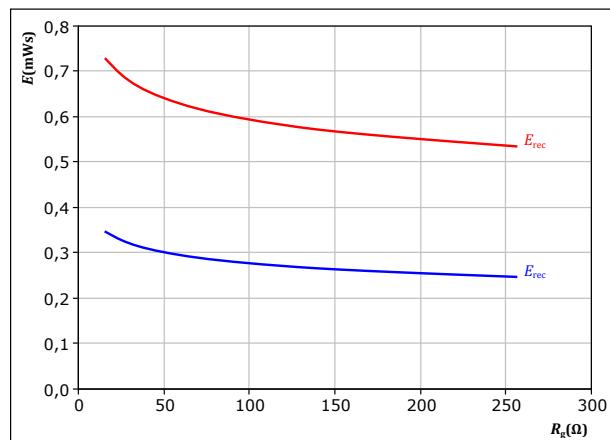
$$T_f: \quad \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{---} & 150^\circ\text{C} \end{array}$$

FWD

figure 12.

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ I_c &= 8 \text{ A} \end{aligned}$$

$$T_f: \quad \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{---} & 150^\circ\text{C} \end{array}$$

FWD

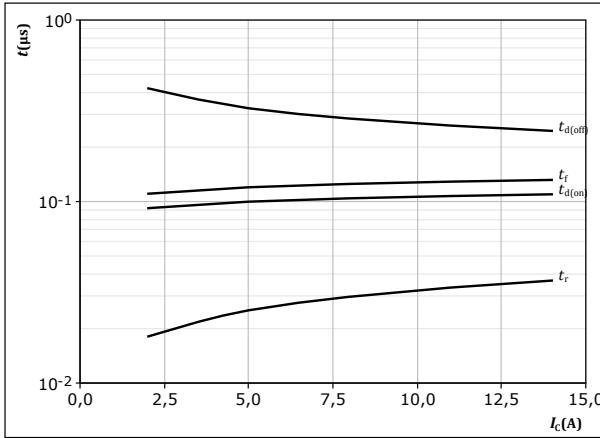


Vincotech

Inverter Switching Characteristics

figure 13. IGBT

Typical switching times as a function of collector current
 $t = f(I_C)$

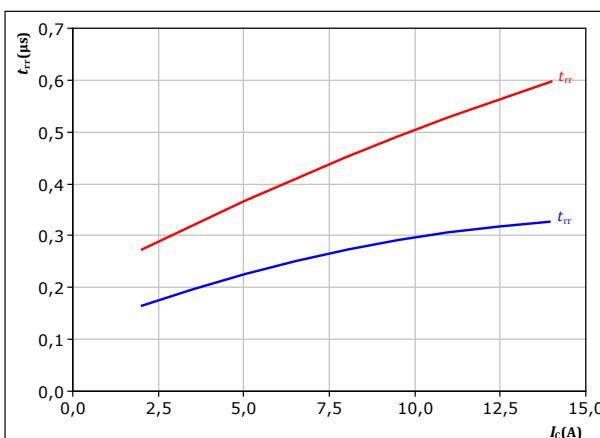


With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 64 \Omega$
 $R_{goff} = 64 \Omega$

figure 15. FWD

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$

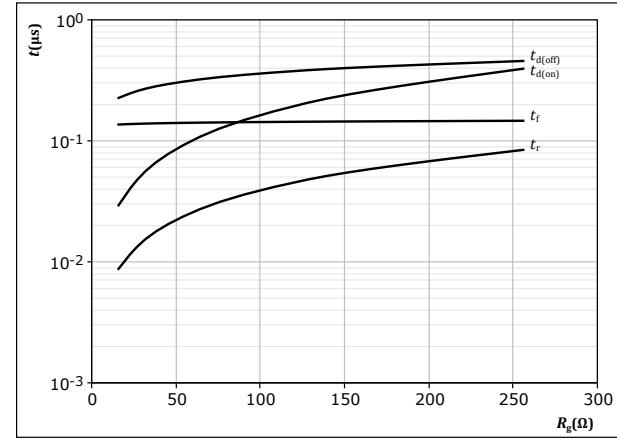


With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 64 \Omega$

figure 14. IGBT

Typical switching times as a function of gate resistor
 $t = f(R_g)$

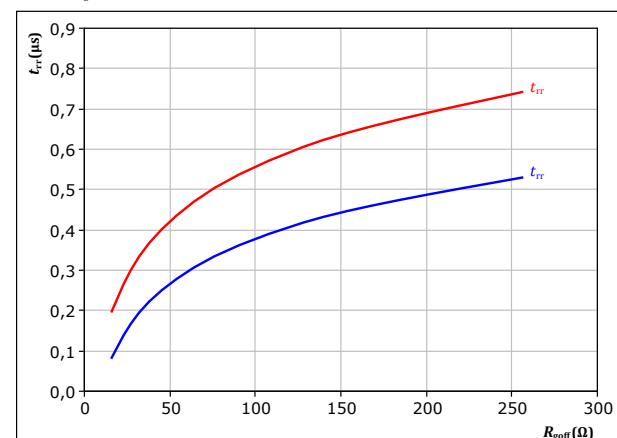


With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 8 \text{ A}$

figure 16. FWD

Typical reverse recovery time as a function of IGBT turn off gate resistor
 $t_{rr} = f(R_{goff})$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 8 \text{ A}$



Vincotech

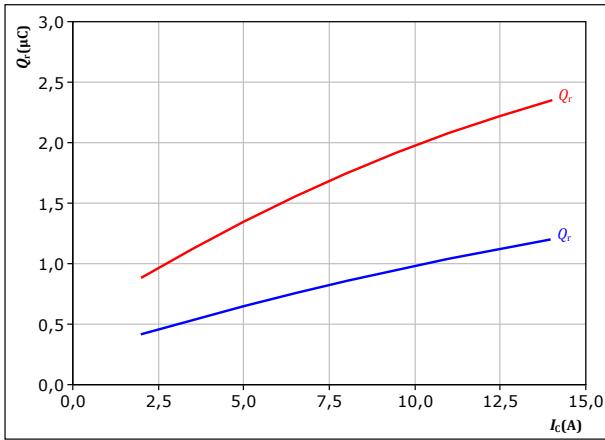
Inverter Switching Characteristics

figure 17.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ R_{gon} &= 64 \Omega \end{aligned}$$

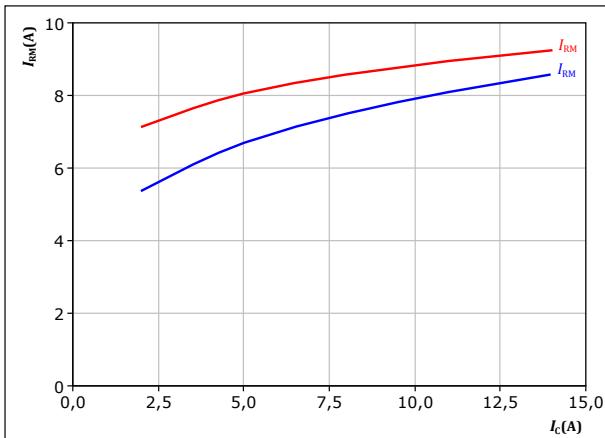
$$T_f: \quad \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{---} & 150^\circ\text{C} \end{array}$$

figure 19.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ R_{gon} &= 64 \Omega \end{aligned}$$

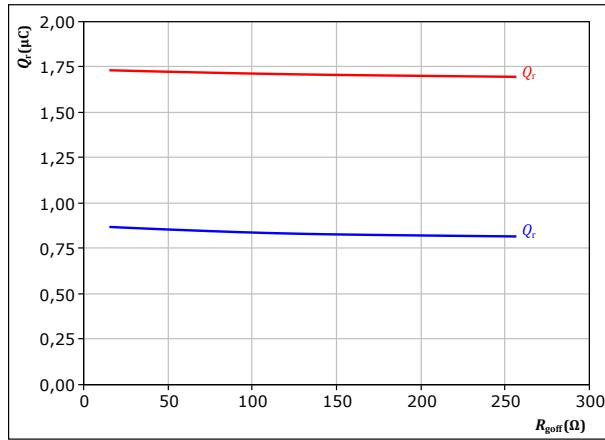
$$T_f: \quad \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{---} & 150^\circ\text{C} \end{array}$$

figure 18.

FWD

Typical recovered charge as a function of turn off gate resistor

$$Q_r = f(R_{gooff})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ I_c &= 8 \text{ A} \end{aligned}$$

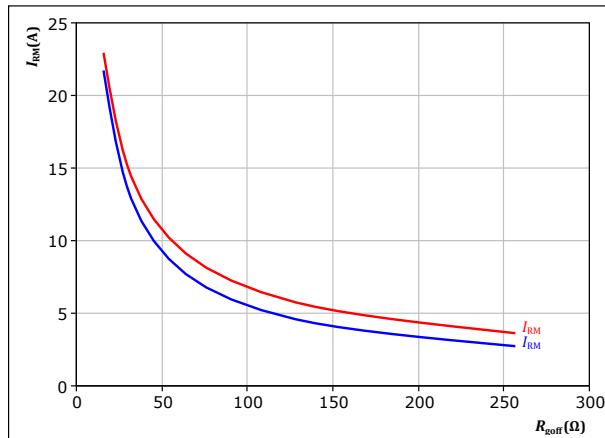
$$T_f: \quad \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{---} & 150^\circ\text{C} \end{array}$$

figure 20.

FWD

Typical peak reverse recovery current as a function of turn off gate resistor

$$I_{RM} = f(R_{gooff})$$



With an inductive load at

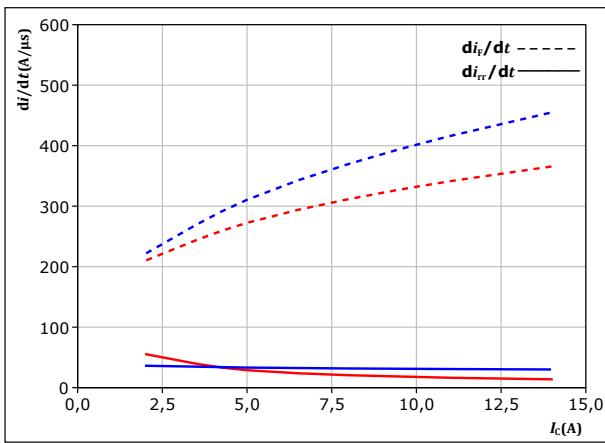
$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ I_c &= 8 \text{ A} \end{aligned}$$

$$T_f: \quad \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{---} & 150^\circ\text{C} \end{array}$$

Inverter Switching Characteristics

figure 21.**FWD**

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_{rr}/dt = f(I_c)$



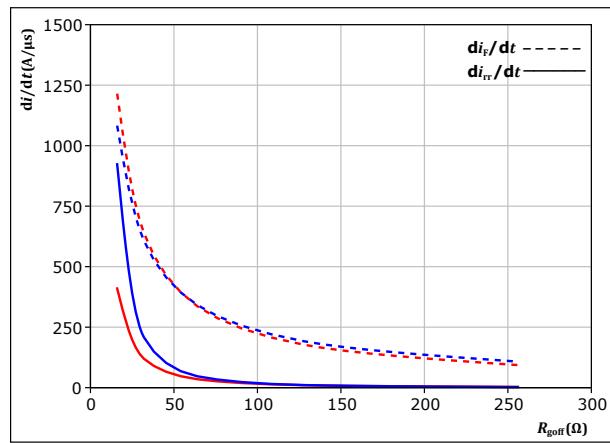
With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 64$ Ω

$T_j = 25^\circ\text{C}$ (blue line)
 $T_j = 150^\circ\text{C}$ (red line)

figure 22.**FWD**

Typical rate of fall of forward and reverse recovery current as a function of turn off gate resistor
 $di_f/dt, di_{rr}/dt = f(R_{goff})$



With an inductive load at

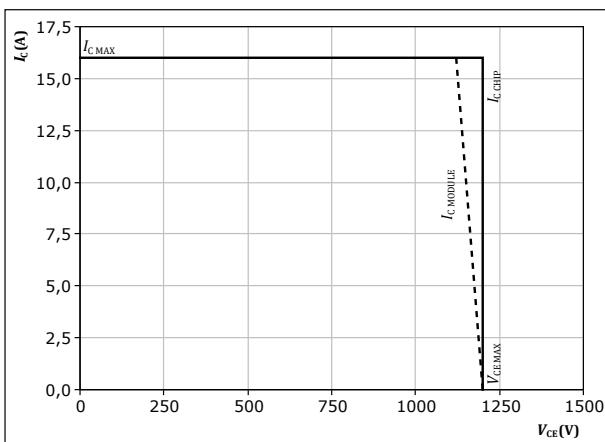
$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 8$ A

$T_j = 25^\circ\text{C}$ (blue line)
 $T_j = 150^\circ\text{C}$ (red line)

figure 23.**IGBT**

Reverse bias safe operating area

$I_c = f(V_{CE})$



At $T_j = 150^\circ\text{C}$
 $R_{gon} = 64$ Ω
 $R_{goff} = 64$ Ω

Inverter Switching Definitions

figure 24. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

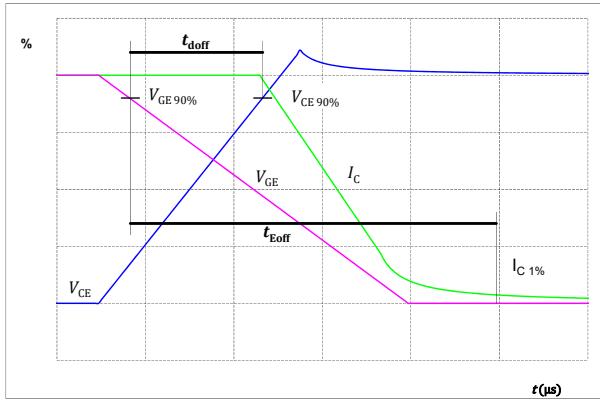


figure 26. IGBT

Turn-off Switching Waveforms & definition of t_f

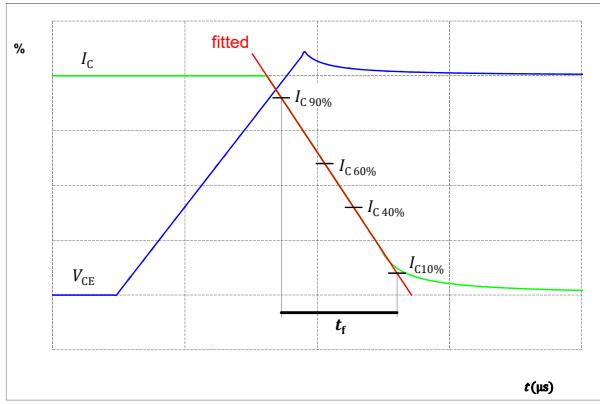


figure 25. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

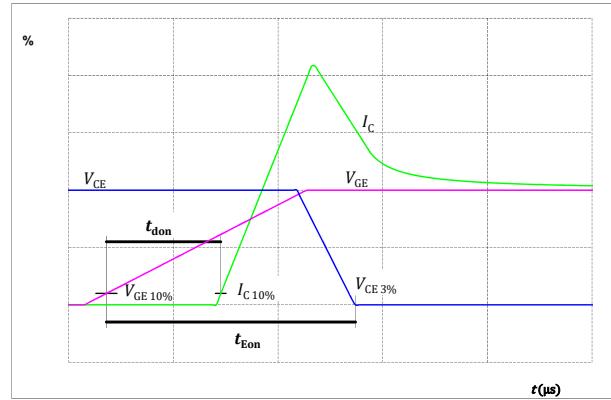
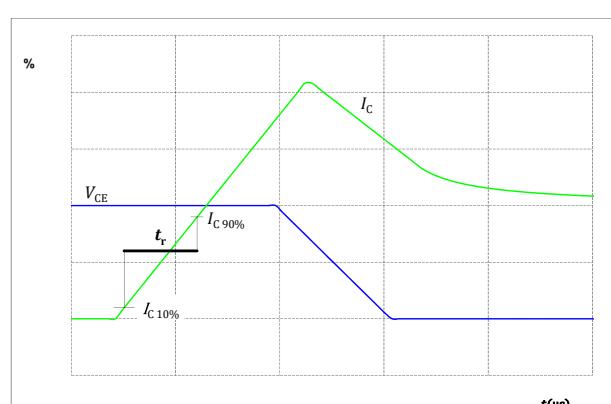


figure 27. IGBT

Turn-on Switching Waveforms & definition of t_r



Inverter Switching Definitions

figure 28.

Turn-off Switching Waveforms & definition of t_{tr}

FWD

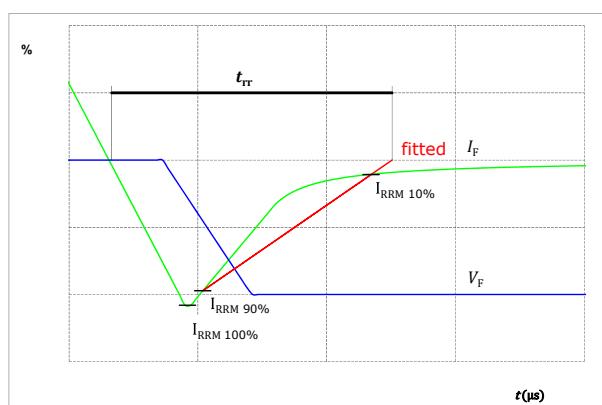
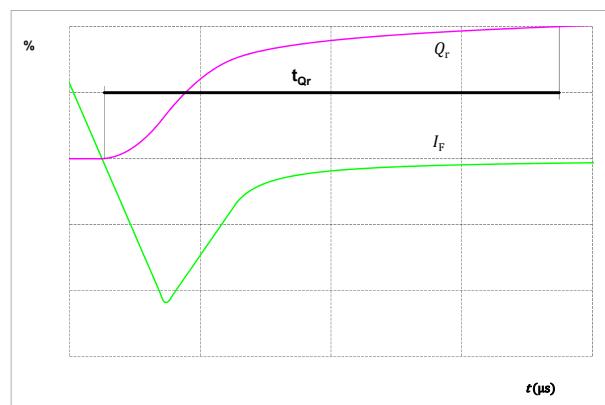


figure 29.

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)

FWD

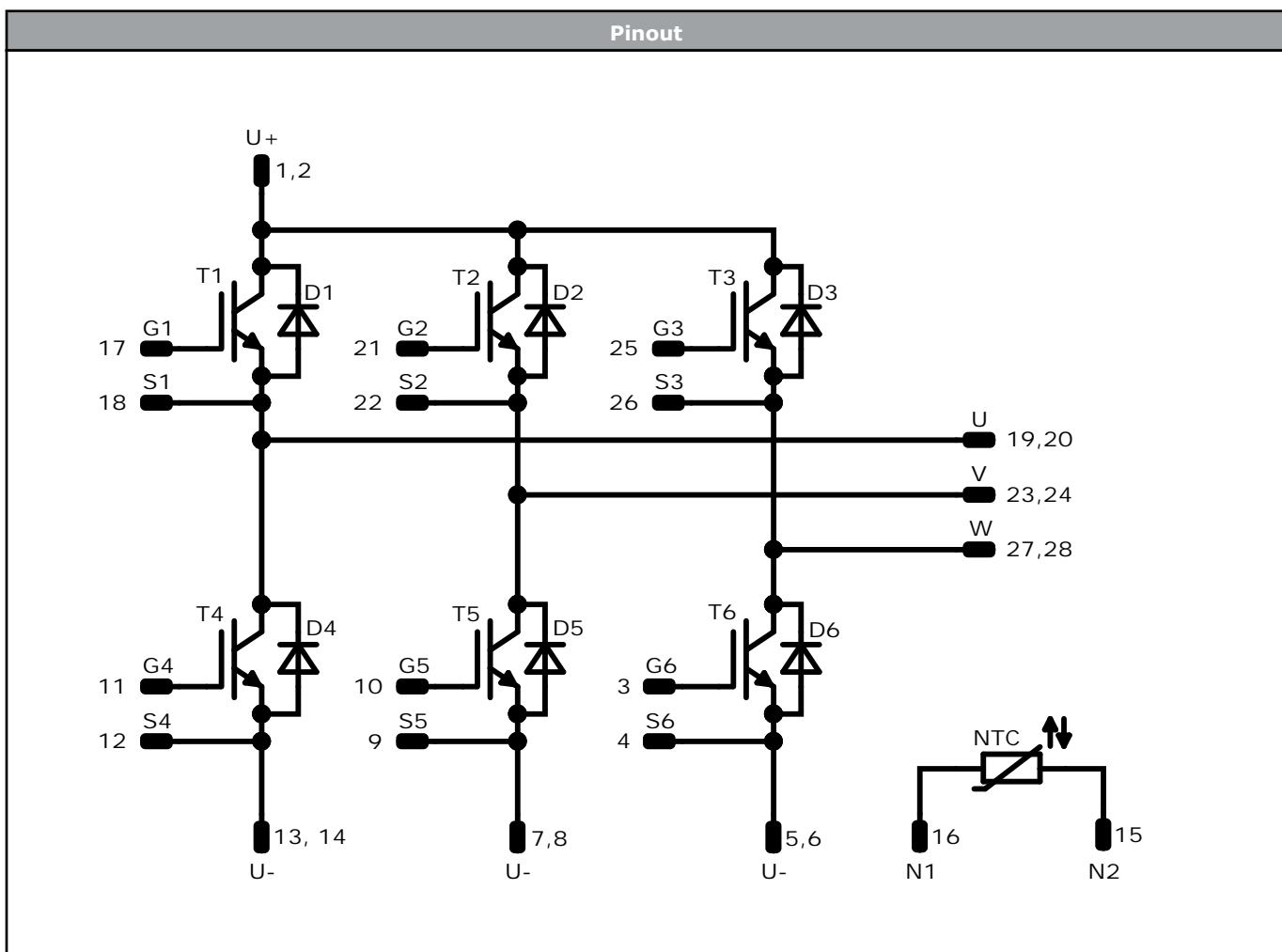




Vincotech

| Ordering Code | | | | | | | | | |
|---------------------------------------|-------------------------|-------------|----------|------------------------|------|--------|--|--|--|
| Version | | | | Ordering Code | | | | | |
| Without thermal paste | | | | V23990-P707-F40-PM | | | | | |
| With thermal paste (3,4 W/mK, PSX-P7) | | | | V23990-P707-F40-/3/-PM | | | | | |
| Marking | | | | | | | | | |
| Text | VIN | Date code | Type&Ver | UL | Lot | Serial | | | |
| | VIN WWYY ULLLSSSS | VIN WWYY | TTTTTTVV | UL | LLLL | SSSS | | | |
| | Type&Ver | Lot number | Serial | Date code | | | | | |
| | TTTTTTVV | LLLLL | SSSS | WWYY | | | | | |
| Outline | | | | | | | | | |
| Pin table [mm] | | | | | | | | | |
| Pin | X | Y | Function | | | | | | |
| 1 | 53 | 0 | U+ | | | | | | |
| 2 | 50 | 0 | U+ | | | | | | |
| 3 | 43 | 0 | G6 | | | | | | |
| 4 | 40 | 0 | S6 | | | | | | |
| 5 | 37 | 0 | U- | | | | | | |
| 6 | 34,1 | 0 | U- | | | | | | |
| 7 | 31 | 0 | U- | | | | | | |
| 8 | 28,1 | 0 | U- | | | | | | |
| 9 | 24,05 | 0 | S5 | | | | | | |
| 10 | 21,05 | 0 | G5 | | | | | | |
| 11 | 17 | 0 | G4 | | | | | | |
| 12 | 12,95 | 0 | S4 | | | | | | |
| 13 | 8,9 | 0 | U- | | | | | | |
| 14 | 6 | 0 | U- | | | | | | |
| 15 | 3 | 0 | N2 | | | | | | |
| 16 | 0 | 0 | N1 | | | | | | |
| 17 | 0 | 7 | G1 | | | | | | |
| 18 | 3 | 7 | S1 | | | | | | |
| 19 | 7,2 | 7 | U | | | | | | |
| 20 | 10,2 | 7 | U | | | | | | |
| 21 | 17,2 | 7 | G2 | | | | | | |
| 22 | 20,2 | 7 | S2 | | | | | | |
| 23 | 29,75 | 7 | V | | | | | | |
| 24 | 32,75 | 7 | V | | | | | | |
| 25 | 39,75 | 7 | G3 | | | | | | |
| 26 | 42,75 | 7 | S3 | | | | | | |
| 27 | 47 | 7 | W | | | | | | |
| 28 | 50 | 7 | W | | | | | | |

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| Identification | | | | | |
|------------------------|------------------|----------------|----------------|-----------------|----------------|
| ID | Component | Voltage | Current | Function | Comment |
| T4, T1, T5, T2, T6, T3 | IGBT | 1200 V | 8 A | Inverter Switch | |
| D1, D4, D2, D5, D3, D6 | FWD | 1200 V | 10 A | Inverter Diode | |
| NTC | Thermistor | | | Thermistor | |



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| Packaging instruction | | | | |
|--------------------------------------|------|----------|------|--------|
| Standard packaging quantity (SPQ) 80 | >SPQ | Standard | <SPQ | Sample |

| Handling instruction | | | | |
|--|--|--|--|--|
| Handling instructions for flow90 1 packages see vincotech.com website. | | | | |

| Package data | | | | |
|---|--|--|--|--|
| Package data for flow90 1 packages see vincotech.com website. | | | | |

| Vincotech thermistor reference | | | | |
|--|--|--|--|--|
| See Vincotech thermistor reference table at vincotech.com website. | | | | |

| UL recognition and file number | | | | |
|---|--|--|--|--|
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website. | | | | |



| Document No.: | Date: | Modification: | Pages |
|--------------------------|--------------|---|--------------|
| V23990-P707-F40-PM-D2-14 | 20 Sep. 2021 | New Datasheet format, module is unchanged Introduce Rth values with PSX-P7 TIM | |

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